-200mA / -30V Low V_{CE} (sat) Digital transistors (with built-in resistors)

DTB713ZE / DTB713ZM

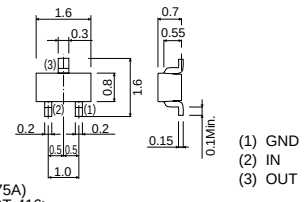
●Applications
Inverter, Interface, Driver

●Feature
1) V_{CE} (sat) is lower than conventional products.
2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
3) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
4) Only the on / off conditions need to be set for operation, making the device design easy.

●Structure
PNP epitaxial plannar silicon transistor
(Resistor built-in type)

●External dimensions (Unit : mm)

DTB713ZE

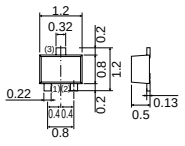


EMT3
JEITA No. (SC-75A)
JEDEC No. <SOT-416>

Each lead has same dimensions

Abbreviated symbol : P11

DTB713ZM



VMT3

Each lead has same dimensions

Abbreviated symbol : P11

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits		Unit
		DTB713ZE	DTB713ZM	
Supply voltage	V_{CC}	−30		V
Input voltage	V_{IN}	−10 to +5		V
Collector current *1	$I_{C\ (max)}$	−200		mA
Power dissipation *2	P_D	150		mW
Junction temperature	Tj	150		℃
Storage temperature	Tstg	−55 to +150		℃

*1 Characteristics of built-in transistor.
*2 Each terminal mounted on a recommended land.

●Packaging specifications

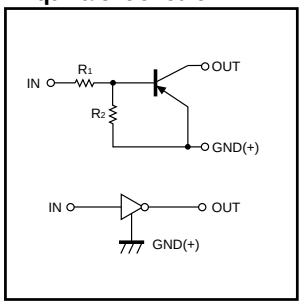
	Package	EMT3	VMT3
	Packaging type	Taping	Taping
	Code	TL	T2L
Part No.	Basic ordering unit (pieces)	3000	8000
DTB713ZE		○	–
DTB713ZM		–	○

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	–	–	−0.3	V	V_{CC}=−5V, I_O=−100μA
	$V_{I(on)}$	−2.5	–	–		V_O=−0.3V, I_O=−20mA
Output voltage	$V_{O(on)}$	–	−70	−300	mV	I_O/I_I=−50mA / −2.5mA
Input current	I_I	–	–	−6.4	mA	V_I= −5V
Output current	$I_{O(off)}$	–	–	−0.5	μA	V_{CC}=−30V, V_I=0V
DC current gain	G_I	140	–	–	–	V_O=−2V, I_O=−100mA
Transition frequency *	f_T	–	260	–	MHz	V_{CE}=−10V, I_E=5mA, f=100MHz
Input resistance	R_1	0.7	1.0	1.3	kΩ	–
Resistance ratio	R_2/R_1	8.0	10	12	–	–

* Characteristics of built-in transistor.

●Equivalent circuit



R_1=1.0kΩ / R_2=10kΩ

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